

Fractal Superconductivity near Localization Threshold

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Superconductivity v/s Localization

- Granular systems with Coulomb interaction

K.Efetov 1980 et al

- Coulomb-induced suppression of T_c in uniform films

A.Finkelstein 1987 et al

- Competition of Cooper pairing and localization (no Coulomb)

Imry-Strongin, Ma-Lee, Kotliar-Kapitulnik, Bulaevsky-Sadovsky(mid-80's)

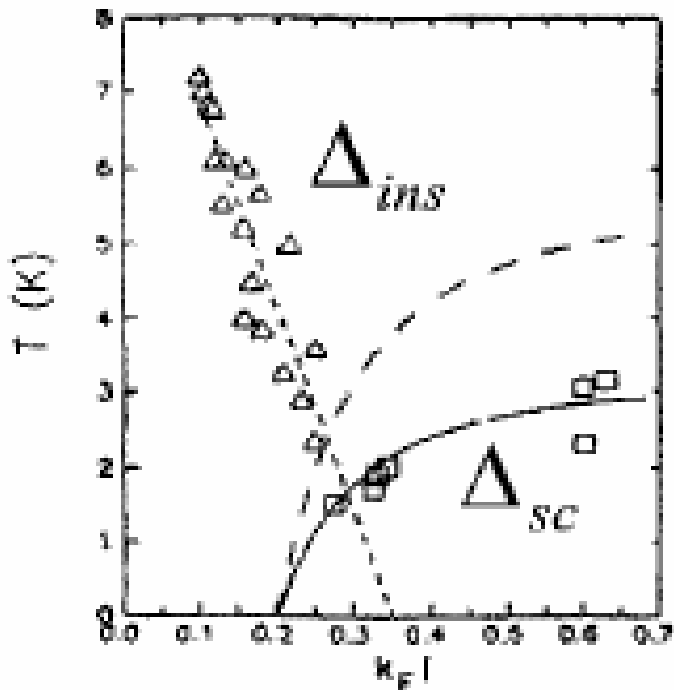
Ghosal, Randeria, Trivedi 2001

There will be no grains and no Coulomb in this talk !

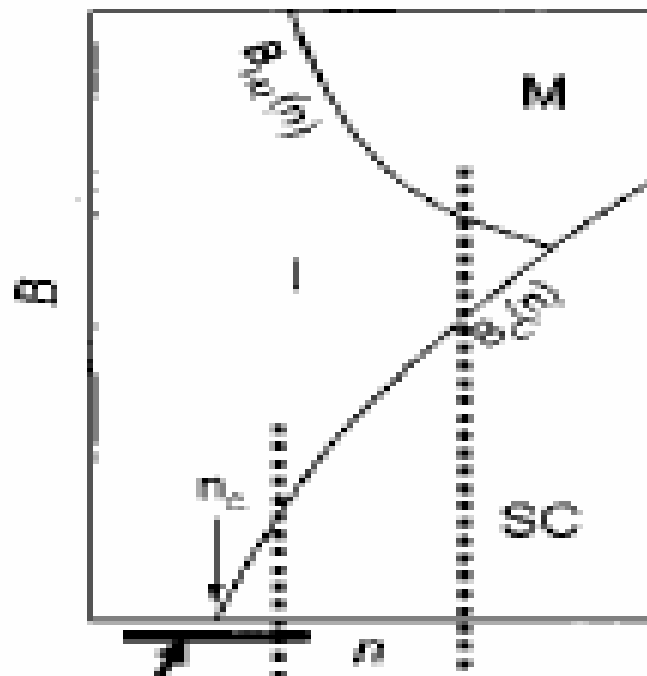
Plan of the talk

1. Motivation from experiments
2. Hard-gap insulator due to electron pairing on localized states
3. BCS-like theory for critical eigenstates
4. S-I transition region and pseudogap

Experimental puzzle: Localized Cooper pairs

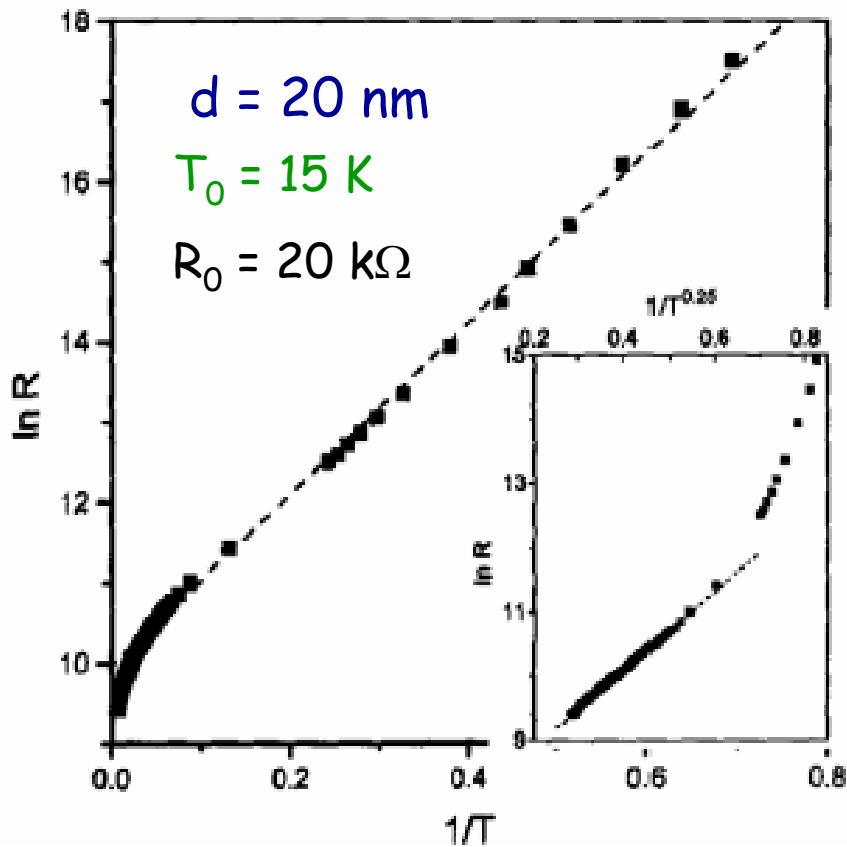


D.Shahar & Z.Ovadyahu
amorphous InO 1992

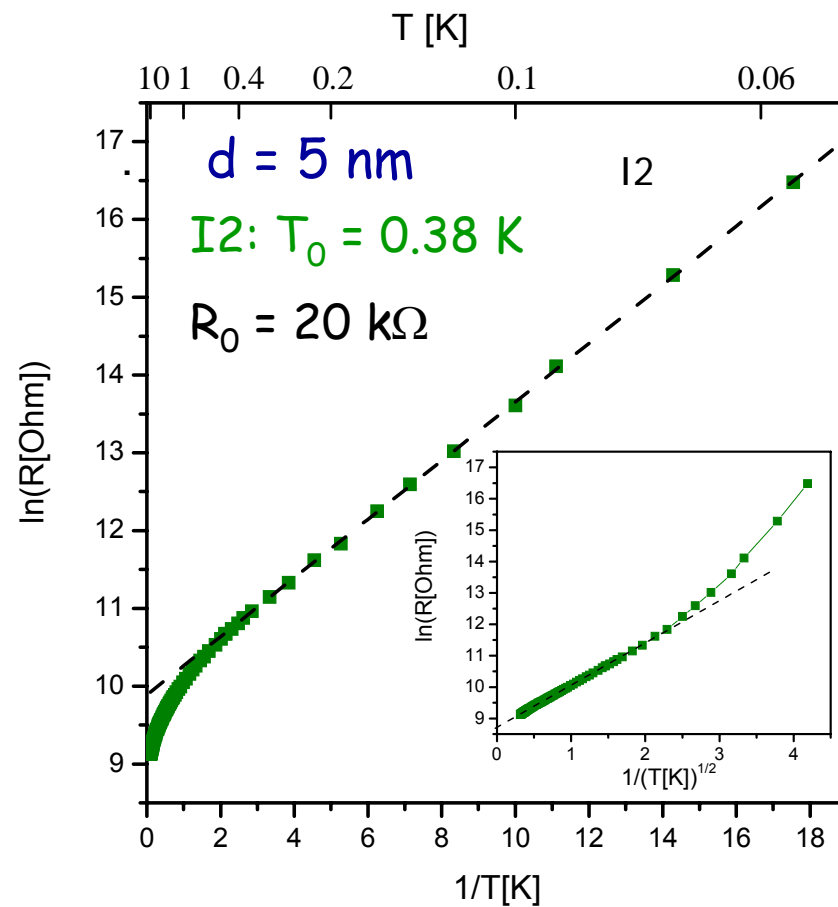


V.Gantmakher et al InO
D.Shahar et al InO
T.Baturina et al TiN

Strongly insulating InO and nearly-critical TiN

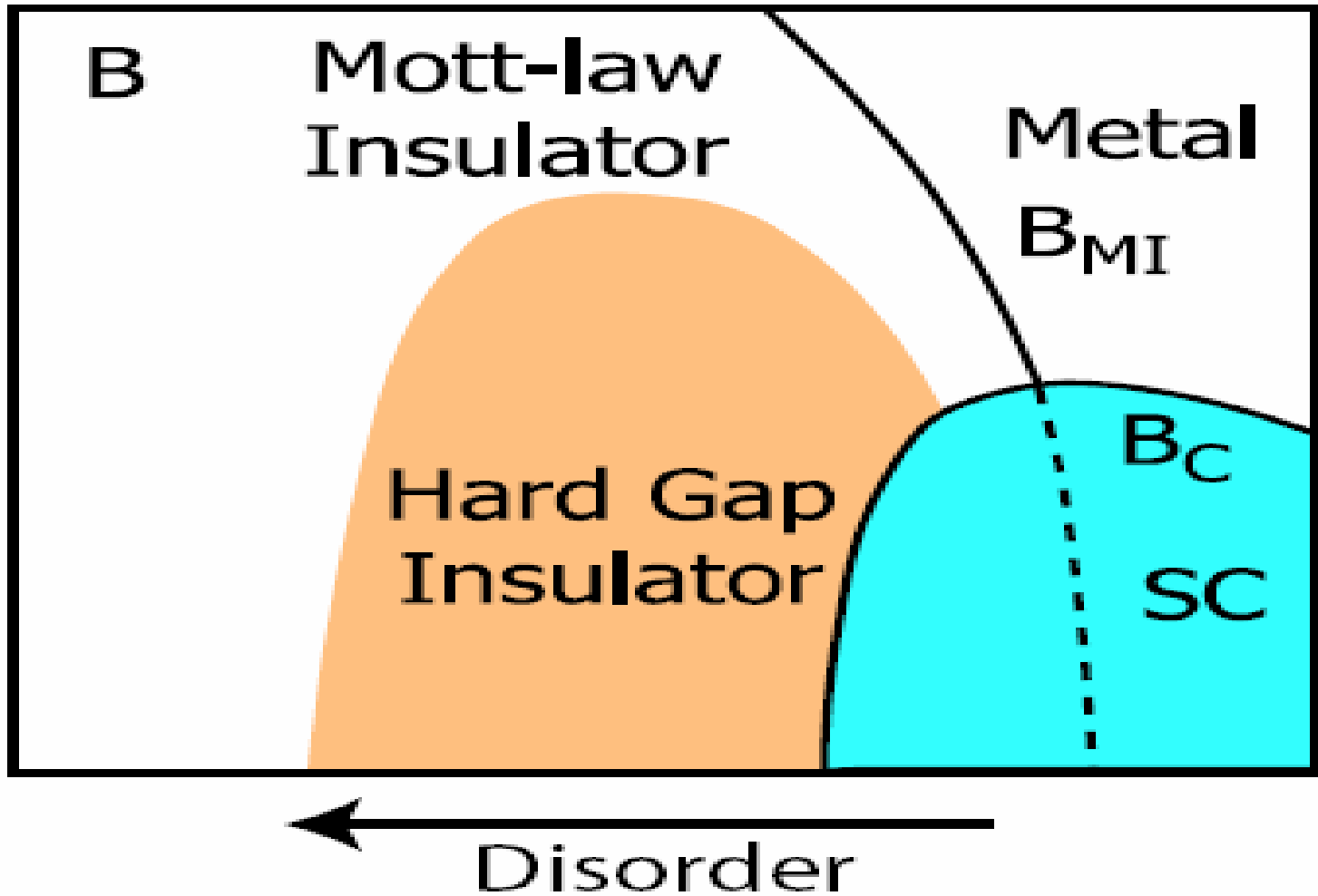


Kowal-Ovadyahu 1994



Baturina et al 2007

Phase Diagram



Theoretical model

Simplest BCS attraction model,
but for localized electrons

$$H = H_{\text{kin}} - g \Psi_{\uparrow}^{\dagger} \Psi_{\downarrow}^{\dagger} \Psi_{\downarrow} \Psi_{\uparrow}$$

$$\Psi = \sum c_j \Psi_j(r)$$

Basis of localized eigenfunctions

M. Ma and P. Lee (1985)

Localization length L_{loc} is **finite but large**

$$H = \sum_{j\sigma} \xi_j c_{j\sigma}^\dagger c_{j\sigma} - \frac{\lambda}{\nu_0} \sum_{i,j,k,l} M_{ijkl} c_{i\uparrow}^\dagger c_{j\downarrow}^\dagger c_{k\uparrow} c_{l\downarrow},$$

where

$$M_{ijkl} = \int d\mathbf{r} \psi_i(\mathbf{r}) \psi_j(\mathbf{r}) \psi_k(\mathbf{r}) \psi_l(\mathbf{r})$$

$$\lambda = g\nu_0$$

$$M_{ij} = \int \psi_i^2(\mathbf{r}) \psi_j^2(\mathbf{r}) d^d r$$

$$M_j = \int \psi_j^4(\mathbf{r}) d^d r \propto L_{loc}^{-D_2}$$

$$D_2 = 1.30 \pm 0.05$$

All other (off-diagonal) terms: beyond BCS MFA

INSULATING STATE AT LARGE $\delta_L = (\nu_0 L_{loc}^3)^{-1}$

Typical value of superdiagonal matrix element:

$$\bar{M} = L_0^{-3} (L_{loc}/L_0)^{-D_2}$$

where L_0 is the short-scale cutoff length of the fractal behaviour.

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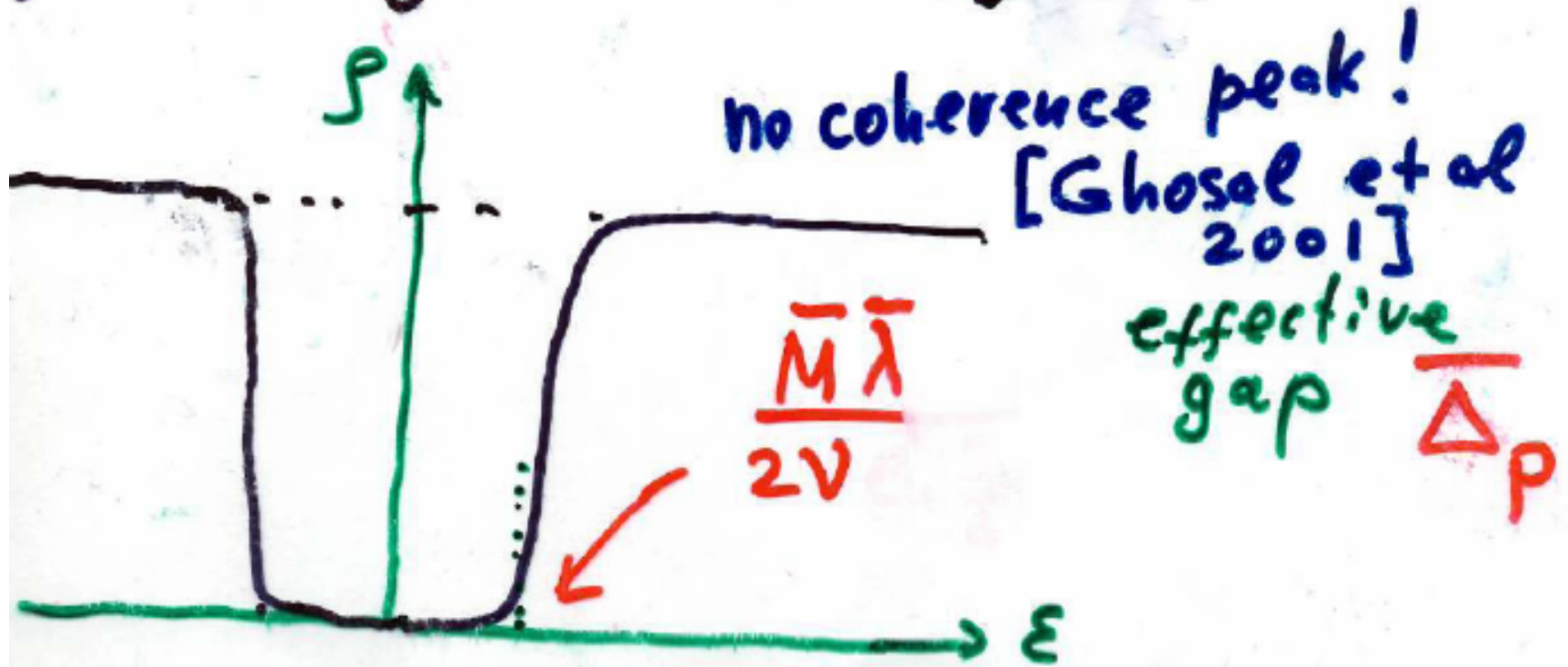
$$\Delta_P = \frac{\lambda}{2} E_0 \left(\frac{L_0}{L_{loc}} \right)^{D_2} \propto (E_m - E_F)^{\nu D_2}$$

where

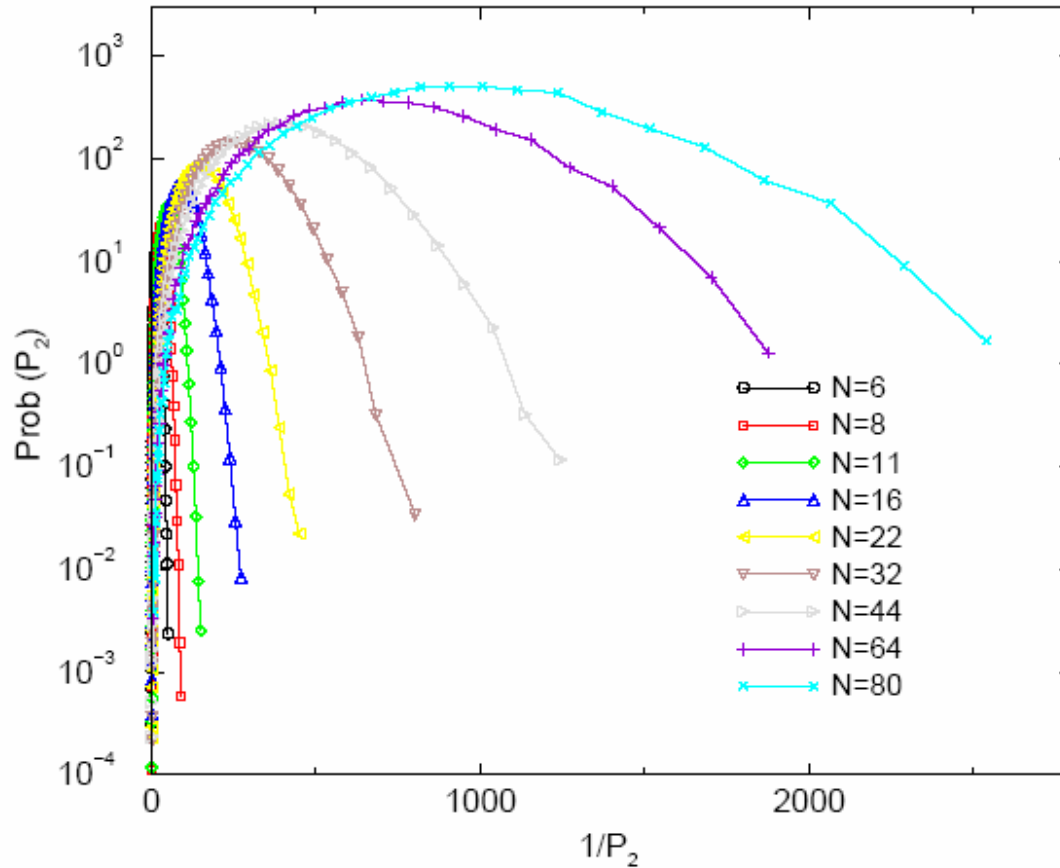
$$E_0 = \frac{1}{\nu_0 L_0^3} \ll E_F$$

Average Density of States

$$\rho(\epsilon) = \nu \int_0^{\infty} \mathcal{P}(M) \theta\left(\epsilon - \frac{M\bar{\lambda}}{2\nu}\right) dM$$

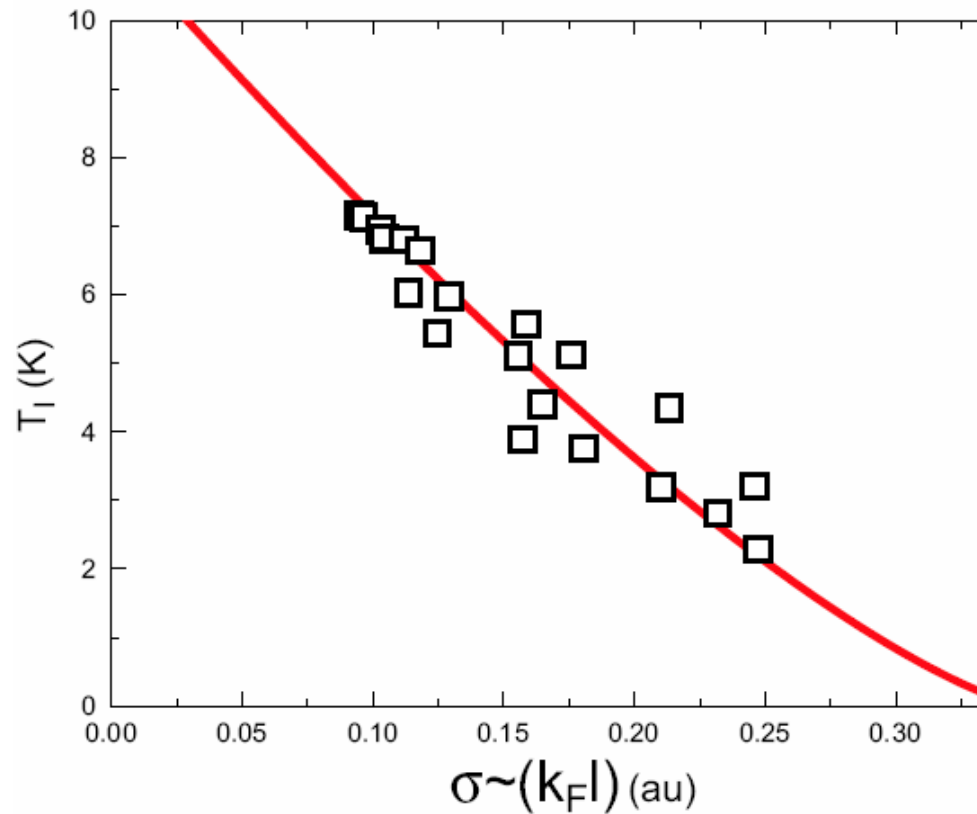


P(M) distribution



A. Mildenberger
and A. Mirlin, private
correspondence
(Critical Ensemble)

Activation energy T_1 , from Shahar-Ovadyahu exp. and fit to theory



Superconductivity at the Localization Threshold: $T_c \gg \delta_L$

Now we will consider the case of Fermi energy very close to the mobility edge:

single-electron states are extended **but fractal**
and populate small fraction of the whole volume

**How BCS theory should be modified to account
for eigenstates fractality ?**

Mean-Field Eq. for T_c

$$\Delta(r) = \int K_T(r, r') \Delta(r') d^d r' \quad (9)$$

where kernel \hat{K}_T is equal to

$$K_T(r, r') = \frac{\lambda}{2\nu_0} \sum_{ij} \frac{\tanh \frac{\xi_i}{2T} + \tanh \frac{\xi_j}{2T}}{\xi_i + \xi_j} \psi_i(r) \psi_j(r) \psi_i(r') \psi_j(r') \quad (10)$$

Standard averaging over space $\Delta(r) \rightarrow \bar{\Delta}$ leads to "Anderson theorem" result: totally incorrect in the present situation.

The reason: critical eigenstates $\psi_j(r)$ are strongly correlated in real 3D space, they fill some small **submanifold** of the whole space only.

In fact one should define T_c as the divergence temperature of the Cooper ladder

$$\mathcal{C} = (1 - \hat{K})^{-1}$$

Thus averaging procedure should be applied to \mathcal{C} instead of K

We expand \mathcal{C} in powers of K and average over disorder realizations. Keeping main sequence of resulting diagrams only, we come to the following equation for determination of T_c :

$$\Phi(\xi) = \frac{\lambda}{2} \int \frac{d\xi' \tanh(\xi'/2T)}{\xi'} M(\xi - \xi') \Phi(\xi') \quad (11)$$

$$M(\omega) = \mathcal{V} \overline{M_{ij}} = \int \overline{\psi_i^2(r) \psi_j^2(r)} d^d r \quad \text{for} \quad |\xi_i - \xi_j| = \omega$$

For critical eigenstates

$$L_{loc} \rightarrow \infty$$

one finds

$$M(\omega) = \left(\frac{E_0}{\omega} \right)^\gamma$$

where

$$\gamma = 1 - \frac{D_2}{d}$$

is a measure of fractality

Usual "dirty superconductor":

$$M(\omega) = 1 \quad \gamma = 0$$

3D Anderson model: $\gamma = 0.57$

The above equation for T_c is equivalent to the neglect in the Hamiltonian "off-diagonal" terms. We employ eigenfunction expansion of the gap function $\Delta(\mathbf{r})$ and use the idea that pairing amplitude

$$F_j = \langle c_{j\uparrow}c_{j\downarrow} \rangle = F(\xi_j)$$

is a smooth function of the bare energy ξ_j :

$$F(\xi) = \frac{\Delta(\xi)}{\sqrt{\Delta^2(\xi) + \xi^2}} \tanh \frac{\sqrt{\Delta^2(\xi) + \xi^2}}{2T}$$

where

$$\Delta(\xi) = \lambda \int d\xi' M(\xi - \xi') F(\xi')$$

Then local pairing amplitude:

$$F(\mathbf{r}) = \sum_j \psi_j^2 \langle c_{j\uparrow}c_{j\downarrow} \rangle \equiv \sum_j \psi_j^2 F_j$$

fluctuates strong in real space

Volume fraction $(T_c/E_0)^{\nu} \ll 1$

Self-consistent "gap equation" in terms of $\Delta(\xi)$:

$$\Delta(\xi) = \lambda \int d\xi' M(\xi - \xi') \frac{\Delta(\xi)}{\sqrt{\Delta^2(\xi) + \xi^2}} \tanh \frac{\sqrt{\Delta^2(\xi) + \xi^2}}{2T}$$

Dimensional analysis of the Mean Field equation:

$$T_c = C(\gamma) E_0 \lambda^{1/\gamma}$$

$$\Delta(\xi = 0, T = 0) = D(\gamma) E_0 \lambda^{1/\gamma}$$

Functions $C(\gamma)$ and $D(\gamma)$ were found numerically:

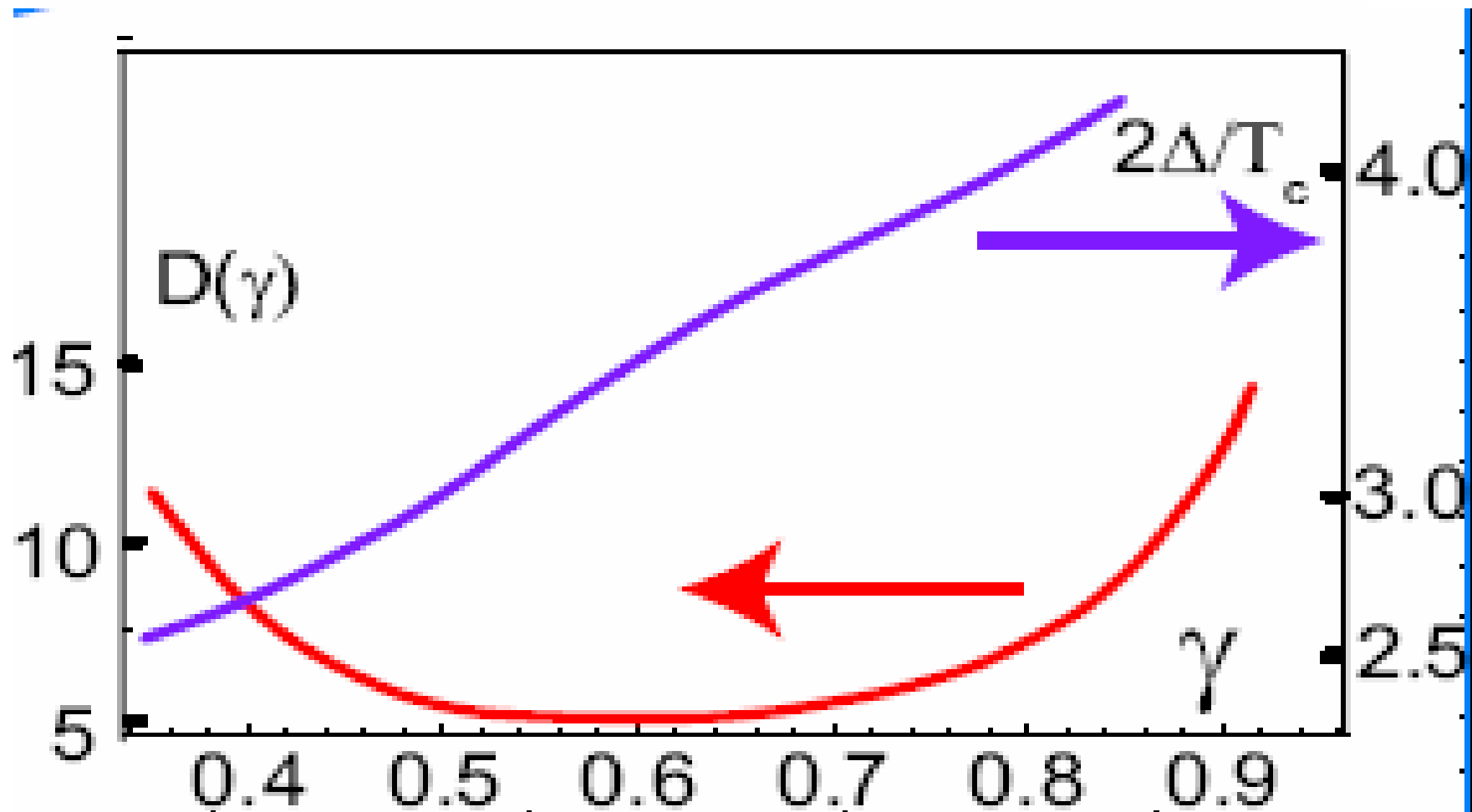
Now we can relate **collective gap** $\Delta(0)$ and **local pairing gap** Δ_P :

$$\Delta_P = \frac{1}{2D^\gamma(\gamma)} \delta_L \left(\frac{\Delta(0)}{\delta_L} \right)^\gamma$$

where $\delta_L = \frac{1}{\nu_0 L_{loc}^3}$ - typical level spacing inside localization volume .

Compare to Matveev-Larkin "parity gap"

$$\Delta_P = \frac{\delta}{2 \log(\delta/\Delta)}$$



Comparison with virial expansion result: disagreement by 10%

I. VERTEX CORRECTIONS

Matrix elements of Cooper interaction are in general

$$M_{ijkl} = \int d^3r \psi_i(r) \psi_j(r) \psi_k(r) \psi_l(r)$$

Quantities M_{ijkl} are random with zero mean, In the second order

$$\delta[\lambda M(\epsilon_1 - \epsilon_2)] = \lambda^2 \nu_0 \int \int d\epsilon_1 d\epsilon_2 R(\epsilon_i, \epsilon_j, \epsilon_1, \epsilon_2) \cdot \frac{\tanh(\beta\epsilon_1/2) - \tanh(\beta\epsilon_2/2)}{2(\epsilon_1 - \epsilon_2)}$$

$$R(\epsilon_i, \epsilon_j, \epsilon_k, \epsilon_l) = \mathcal{V}^3 \overline{M_{ijkl}^2} \sim L_0^3 \left(\frac{E_0}{\omega} \right)^t$$

$$t = 3(1 - d_4/d)$$

and d_4 is the exponent entering expression $P_4 = \int dr (|\psi|^2(r))^4 = \mathcal{V}^{-3d_4/d}$.

$$\delta[\lambda M(\omega)] = \lambda^2 \left(\frac{E_0}{\omega} \right)^{2-3d_4/d}$$

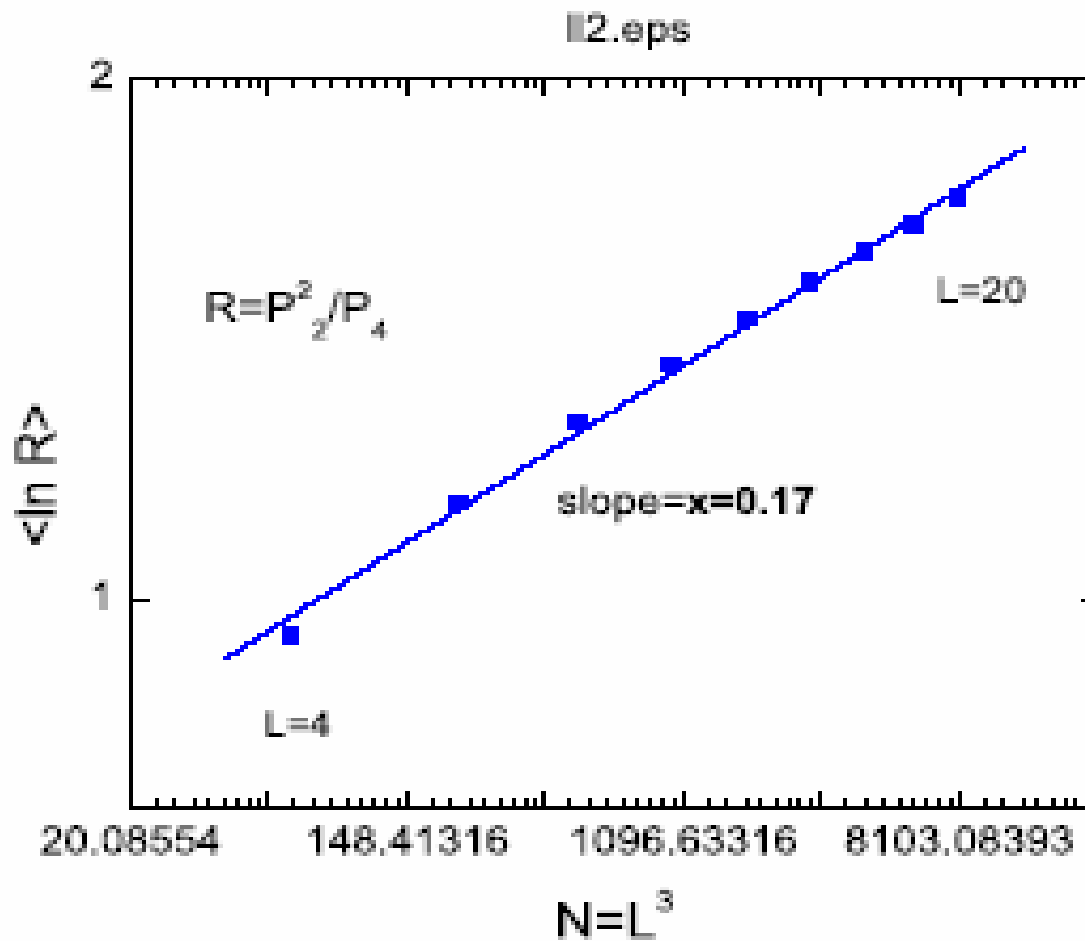
The condition $\delta[\lambda M(\omega)] \ll \lambda M(\omega)$ is fulfilled at $\omega \sim T_c$ if the exponent $x = d_4 - \frac{2}{3}d_2 > 0$, since their ratio scales as

$$\frac{\delta[\lambda M(T_c)]}{\lambda M(T_c)} \sim (T_c/E_0)^x$$

x > 0 always !

3D Anderson: x = 0.17

Numerics for 3D Anderson model:



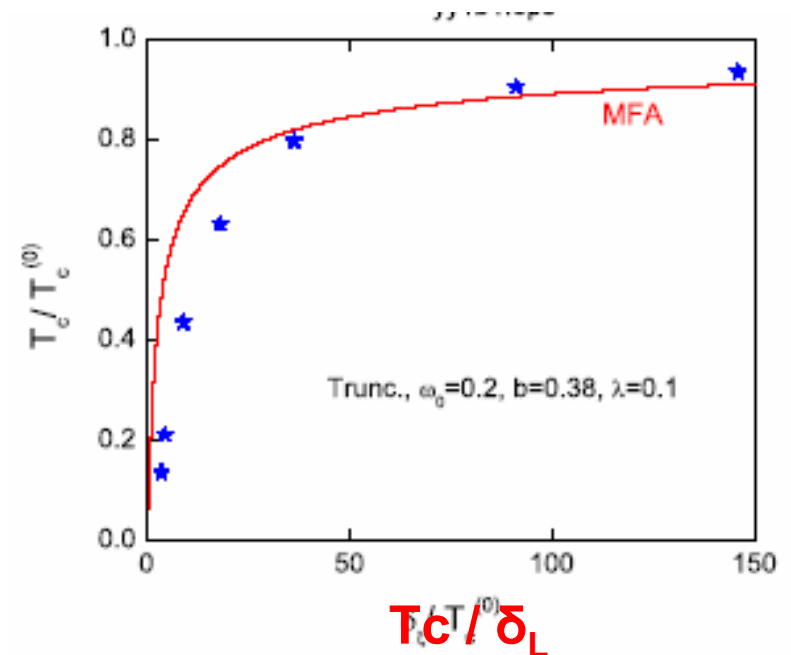
Conclusion:
“diagonal”
approximation
makes sense,
but corrections
are non-negligible

Go deeper into insulator

Level spacing δ_L becomes comparable to T_c

$$M(\omega) = \left(\frac{E_0}{|\omega| + \delta_L} \right)^\gamma$$

$$T_c = T_c^{(0)} \mathcal{T}_\gamma \left(\frac{T_c^{(0)}}{\delta_L} \right)$$



However, this $M(\omega)$ is specific to 1D models only

3D Anderson insulator: $M(\omega)$

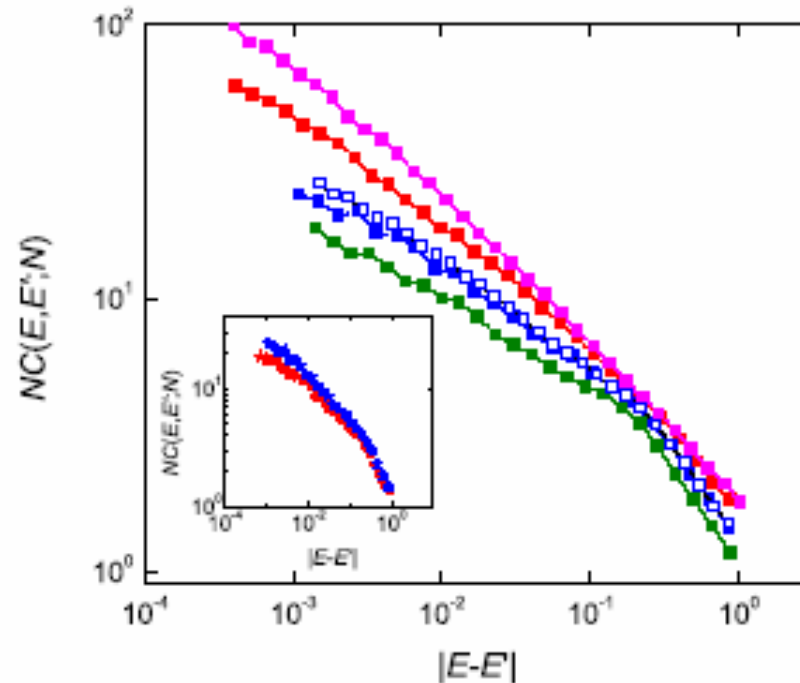
No saturation at $\omega < \delta_L$

Superconductivity with $T_c < \delta_L$ is possible

Then “local gap”

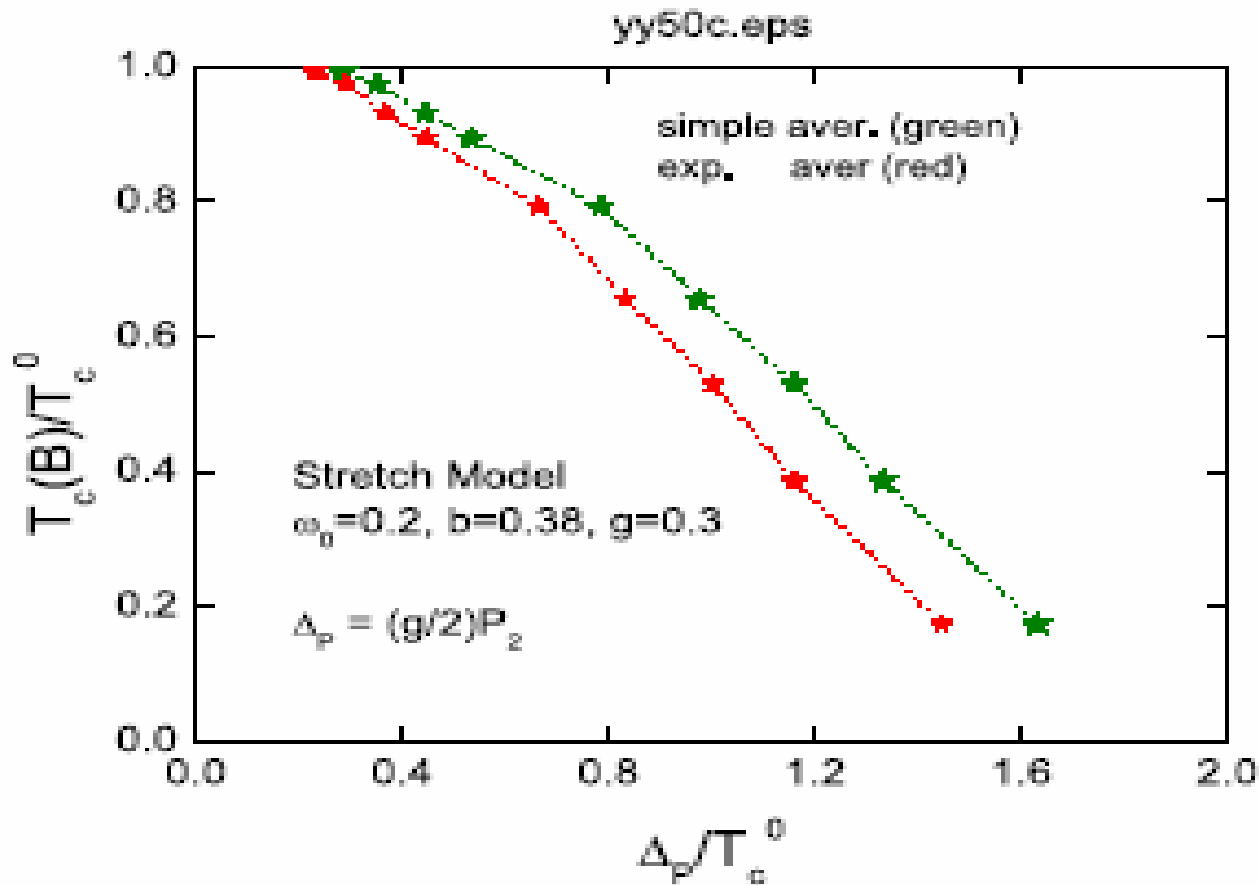
$$\Delta_P = \frac{1}{2D^\gamma(\gamma)} \delta_L \left(\frac{\Delta(0)}{\delta_L} \right)^\gamma$$

exceeds T_c !



Transition temperature v/s Pseudogap

Virial expansion results:

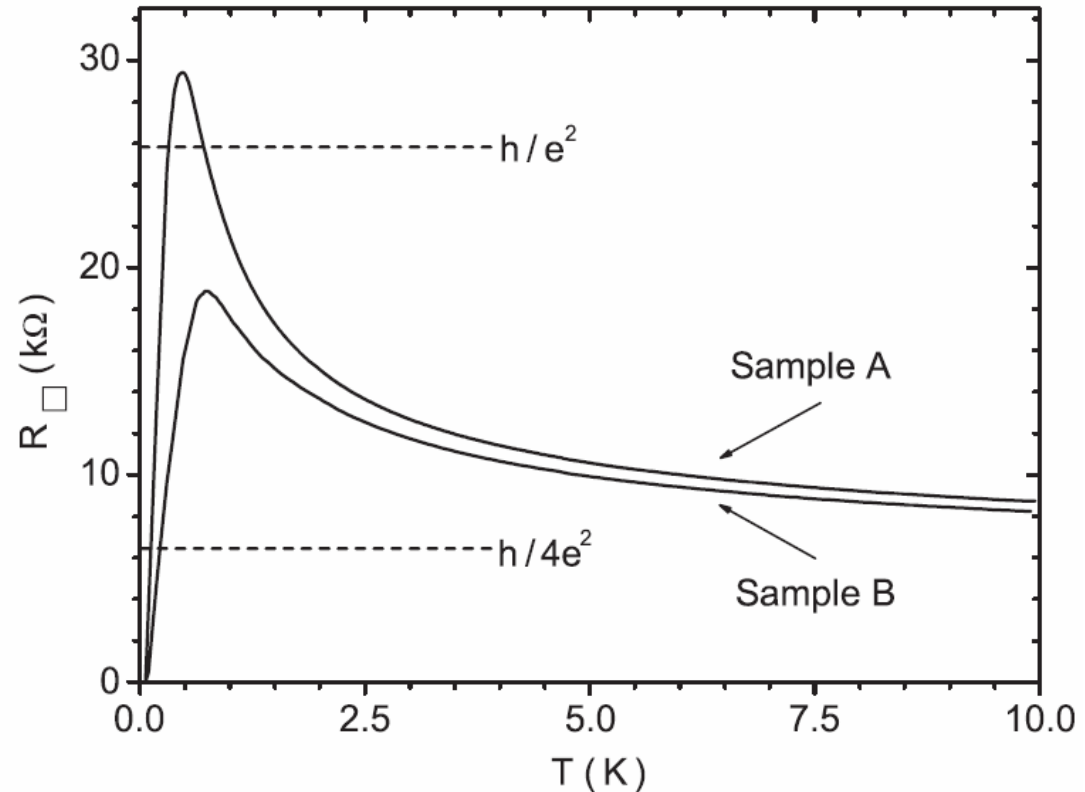


Superconductivity with Pseudogap

The condition $\Delta_p > T_c$

leads to “pseudogap phenomenology” :
a spectral gap opens
above superconductive
transition

With increase of disorder
 Δ_p grows but T_c decreases



Baturina et al , PRL 2007

Major unsolved problems

- 1. Role of Coulomb enhancement near mobility edge ? (this effect was treated by Finkelstein for thin-film case)
- 2. How to include magnetic field into the “fractal” scheme ?

Conclusions

- Pairing of electrons on localized states leads to hard gap and Arrhenius resistivity
- Pairing on nearly-critical states produces fractal superconductivity with relatively high T_c but very small superconductive density
- Pseudogap behaviour is expected near S-I transition, with “insulating gap” exceeding T_c